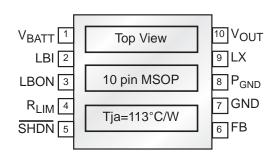


# Ultra-low Quiescent Current, High Efficiency Boost DC-DC Regulator

#### **FEATURES**

- Ultra-low 12µA Quiescent Current
- 700mA Output Current at 2.6V<sub>IN</sub>, 3.3V<sub>OUT</sub>
- 94% Efficiency Possible
- Wide Input Voltage Range: 0.85V to 4.5V
- 3.3V Fixed Output and adjustable 2.5V to 5.0V Output Range
- Internal Synchronous Rectifier for High Efficiency
- 0.3 Charging Switch, 0.3 Synchronous Rectifier
- Anti-Ringing Inductor Switch
- Programmable Inductor Peak Current
- Logic Shutdown Control
- Under Voltage Lock-Out, 0.62V
- Programmable Low Battery Detect
- □ Small 10 pin MSOP Package



#### **APPLICATIONS**

- Digital Still Cameras
- MP3 Players
- PDA's
- Pagers
- Handheld Portable Devices
- Medical Monitors

#### DESCRIPTION

The SP6649 is an ultra-low quiescent current, high efficiency step-up DC-DC converter ideal for single and dual cell alkaline, or Li-lon battery applications such as digital still cameras, PDA's, MP3 players, and other portable devices. The SP6649 combines the high delivery associated with PWM control, and the low quiescent current and excellent light-load efficiency of PFM control. The SP6649 features 12µA quiescent current, synchronous rectification, a 0.3 charging switch, anti-ringing inductor switch, programmable low battery detect, under-voltage lockout and programmable inductor peak current. The device can be controlled by a 1nA active LOW shutdown pin.

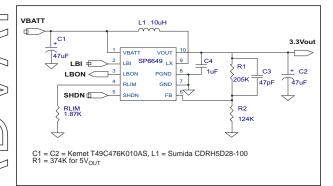


Figure 1. Typical Application Circuit

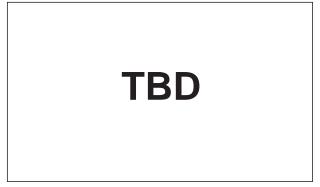


Figure 2. Maximum Load Current in Operation

#### **ABSOLUTE MAXIMUM RATINGS**

These are stress ratings only and functional operation of the device at these ratings or any other above those indicated in the operation sections of the specifications below is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect reliability.

LX, Vo, V <sub>BATT</sub> , LBON, FB to GND pin	0.3 to 6.0V
SHDN, LBÎ	0.3V to V <sub>BATT</sub> +0.5V
Vo, GND, LX Current	1.3A
Reverse V <sub>RATT</sub> Current	220mA
Forward V <sub>RATT</sub> Current	500mA
Storage Temperature	65 °C to 150°C
Operating Temperature	40°C to +85°C
Lead Temperature (Soldering, 10 sec)	300 °C
FSD Rating	

## SPECIFICATIONS

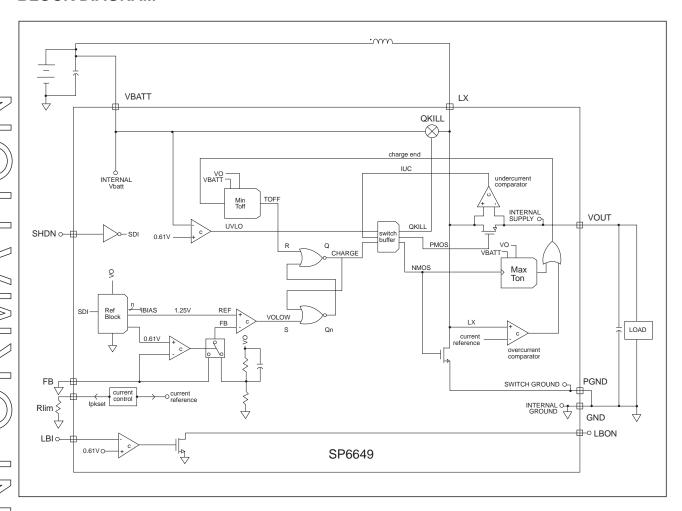
 $V_{BATT} = V_{\overline{SHDN}} = 1.3V, V_{FB} = 0V, I_{LOAD} = 0 \text{mA}, T_{AMB} = -40 ^{\circ}\text{C to} + 85 ^{\circ}\text{C}, V_{OUT} = +3.3V, typical values at 27 ^{\circ}\text{C unless otherwise noted}.$ 

PARAMETER	MIN	TYP	MAX	UNITS	CONDITIONS
Input Voltage Operating Range, V <sub>BATT</sub>	0.7		4.5	V	After Startup
Under Voltage Lock-out/UVLO		0.62		V	
Start-up Input Voltage, V <sub>BATT</sub>		0.85	0.9	V	R <sub>LOAD</sub> = 3k
Output Voltage, V <sub>O</sub>	3.16	3.30	3.44	V	3.3V V <sub>O</sub> preset
Quiescent Current into V <sub>O</sub> , I <sub>QO</sub>		12	22	μΑ	$V_{OUT} = 3.3V$ , $V_{FB} = 1.5V$ , Toggle $\overline{SHDN}$
Quiescent Current into V <sub>BATT</sub> , I <sub>QB</sub>		20	500	nA	V <sub>OUT</sub> = 3.3V, V <sub>FB</sub> = 1.5V
Shutdown Current into V <sub>O,</sub> I <sub>SDO</sub>		1	500	nA	V <sub>SHDN</sub> = 0V
Shutdown Current into V <sub>BATT</sub> , I <sub>SDB</sub>		200	500	nA	$V_{\overline{SHDN}} = 0V, V_{BATT} = 2.6V$
Efficiency, R <sub>LIM</sub> = 4.0K		85 91		% %	V <sub>BATT</sub> = 1.3V, I <sub>OUT</sub> = 50mA V <sub>BATT</sub> = 2.6V, I <sub>OUT</sub> = 100mA
Efficiency, R <sub>LIM</sub> = 1.87K		85 92		% %	$V_{BATT} = 1.3V, I_{OUT} = 100mA$ $V_{BATT} = 2.6V, I_{OUT} = 200mA$
Inductor Current Limit, I <sub>PK</sub>	1.0	1.2	1.4	Α	$R_{LIM} = 1.17k$ , $I_{PK} = 1400/R_{LIM}$
Output Current		250 700		mA mA	$V_{BATT} = 1.3V, R_{LIM} = 1.17k$ $V_{BATT} = 2.6V, R_{LIM} = 1.17k$
		150 400		mA mA	V <sub>BATT</sub> = 1.3V, R <sub>LIM</sub> = 1.87k V <sub>BATT</sub> = 2.6V, R <sub>LIM</sub> = 1.87k
Minimum Off-Time Constant K <sub>OFF</sub>		1.1		V*µs	t <sub>OFF</sub> K <sub>OFF</sub> /(V <sub>OUT</sub> -V <sub>BATT</sub> )
Maximum On-Time Constant K <sub>ON</sub>		3.3		V*µs	t <sub>ON</sub> K <sub>ON</sub> / V <sub>BATT</sub>
N <sub>MOS</sub> Switch Resistance		0.30	0.6		I <sub>NMOS</sub> = 100mA
P <sub>MOS</sub> Switch Resistance		0.30	0.6		I <sub>PMOS</sub> = 100mA
FB Set Voltage, V <sub>FB</sub>	1.20	1.25	1.30	V	External feedback
FB Input Current		1	100	nA	V <sub>FB</sub> =1.3V
LBI Falling Trip Voltage	0.594	0.625	0.656	V	
LBI Hysteresis		25		mV	
Low Output Voltage for LBON, V <sub>OL</sub>			0.4	V	V <sub>BATT</sub> = 1.3V, Isink = 1mA
Leakage current for LBON			500	nA	$V_{BATT} = 1.3V$ , $V_{LBON} = 3.3V$
SHDN Input Voltage V <sub>IL</sub> V <sub>IH</sub> V <sub>IL</sub> V <sub>IH</sub>	1.0 2.0		0.25 0.5	V	$V_{BATT} = 1.3V$ $V_{BATT} = 1.3V$ $V_{BATT} = 2.6V$ $V_{BATT} = 2.6V$
SHDN Input Current		1	100	nA	

### **PIN DESCRIPTION**

	PIN NUMBER	PIN NAME	DESCRIPTION
7	1	$V_{BATT}$	Battery Voltage pin. The startup circuitry runs off of this pin. The operate circuit also uses this voltage to regulate the off-time [ $t_{OFF} = K_{OFF}/(V_{OUT} - V_{BATT})$ ]. When the battery voltage drops below 0.62V after a successful startup the SP6649 goes into an undervoltage lockout mode (UVLO).
	2	LBI	Low Battery Input pin. LBI below 0.61V causes the LBON pin to pull down to ground. Use a resistor divider to program the low voltage threshold for each battery configuration.
	3	LBON	Low Battery Output Not pin. Open drain $N_{\text{MOS}}$ output that sinks current to ground when LBI is below 0.625V.
	4	$R_{LIM}$	Resistor Programmable Inductor Peak Current. By connecting a resistor $R_{\text{LIM}}$ from this pin to ground the inductor peak current is set by $I_{\text{PEAK}}=1400/R_{\text{LIM}}$ . The range for $R_{\text{LIM}}$ is 4.0K (for 350mA) to 1.17K (for 1.2A).
	5	SHDN	Shutdown Not. Tie this pin to $V_{BATT}$ for normal operation. Tie this pin to ground to disable all circuitry inside the chip. In shutdown the output voltage will float down to a diode drop below the battery potential.
	6	FB	External Feedback pin. Connect this pin to GND for fixed $+3.3V$ operation. Connect this pin to a resistor voltage divider between $V_{\text{OUT}}$ and GND for adjustable output operation.
	7	GND	Ground pin for the internal regulator bias currents.
	8	$P_{GND}$	Switch ground pin. The inductor charging current flows out of this pin.
	9	LX	Inductor switching node. Connect one terminal of the inductor to the positive terminal of the battery. Connect the second terminal of the inductor to this pin. The inductor charging current flows into LX, through the internal charging N-channel FET, and out the GND pin.
	10	V <sub>OUT</sub>	Output Voltage pin. The inductor current flows out of this pin during the off-time. It is also the internal regulator voltage supply, and minimum off-time one shot input. Kelvin connect this pin to the positive terminal of the output capacitor.

#### **BLOCK DIAGRAM**



#### THEORY OF OPERATION

# **Detailed Desctiption:**

The SP6649 is a step-up DC-DC converter that starts up with input voltages as low as 0.85V (typically) and operates with input voltages down to 0.62V. The ultra low quiescent current of 12µA provides excellent efficiencies. In addition to the 0.3 internal MOSFET the SP6649 has an internal synchronous rectifier eliminating the need for an external diode. An internal inductive-damping switch significantly reduces inductive ringing. If the supply voltage drops below 0.62V the SP6649 goes into under voltage lock-out opening up the internal switches. An externally programmable low battery detector with open drain output provides the user the ability to monitor the supply voltage. The inductor peak current is externally programmable to allow for a range of inductors.

#### **Control Scheme:**

A minimum off-time, current limited pulse frequency modulation (PFM) control scheme combines the high output power and efficiency of a pulse width modulation (PWM) device with the ultra low quiescent current of the traditional PFM. At low to moderate output loads the PFM control provides a higher efficiencies than traditional PWM converters are capable of delivering. At these loads the switching frequency is determined by a minimum off-time (t<sub>OFF</sub>, <sub>MIN</sub>) and a maximum on-time (t<sub>ON</sub>, <sub>MAX</sub>) where:

 $t_{OFF}$  K  $_{OFF}$  /  $(V_{OUT}$  -  $V_{BATT})$  and  $t_{ON}$  K  $_{ON}$  /  $V_{BATT}$  with  $K_{OFF} = 1.1 V \mu \text{s} \text{ and}$  K  $_{ON}$  = 3.3 V  $\mu \text{s}.$ 

At light loads (plot A in *Figure 3*) the charge cycle will take  $t_{ON,\,MAX}$   $\mu s$ . For a 1V battery this would be:

$$t_{ON,\;MAX}$$
 =  $K_{ON}$  /  $V_{BATT}$  = 3.3 $V\mu s$  /  $1V$  = 3.3 $\mu s$ 

The current built up in the coil during the charge cycle gets fully discharged (discontinuous conduction mode, DCM) When the current in the coil has reached zero the synchronous rectifier switch is opened and the voltage across the coil (from  $V_{BATT}$  to LX) is shorted internally to eliminate inductive ringing.

With increasing load (plot B in *Figure 3*) this inductor damping time becomes shorter (because the output will drop quicker below its regulation point due to the heavier load) up to the point where it becomes zero. If the load increases further the SP6649 enters continuous conduction mode (CCM) where there is always current in the inductor. The charge time is still ton, MAX as long as the inductor peak current limit is not reached (plot C in *Figure 3*). the inductor peak current limit can be programmed by trying a resistor R<sub>LIM</sub> from the R<sub>LIM</sub> pin to ground where:

$$I_{PEAK} = 1400 / R_{LIM}$$

with a maximum recommended  $I_{PEAK}$  of 1.2A (or a minimum  $R_{LIM}$  of 1.17K ).

When the peak current limit is reached the charge time is short-cycled.

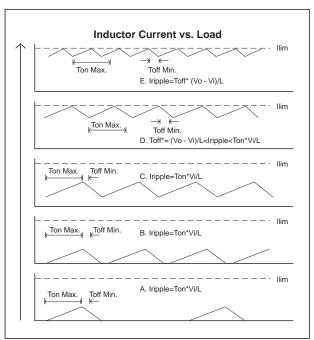


Figure 3. Inductor Current vs. Load

In (plot D of *Figure 3*) the current reaches the peak current limit during the charge cycle but full load is still not reached becuse at the end of the minimum off-time V<sub>OUT</sub> was still not below its regulation point. Finally in plot E the maximum load is reached where the discharge time has shrunk to its minimum allowed value t<sub>OFF,MIN</sub>.

#### PERFORMANCE CHARACTERISTICS

3.3V out, refer to the Circuit in Figure 1, T<sub>AMB</sub>=+25°C.

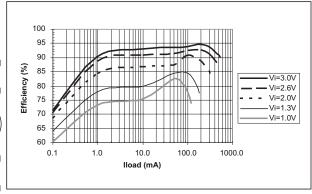


Figure 4. Efficiency vs. Load Current

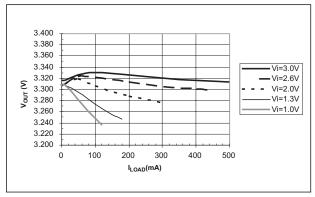


Figure 5. Line/Load Rejection vs. Load Current

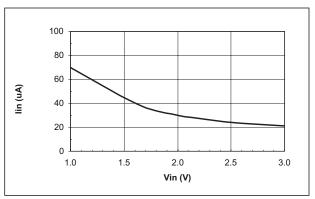


Figure 6. No Load Battery Current

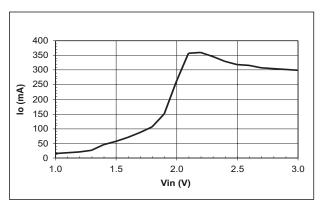


Figure 7. Maximum Resistive Load Current in Startup

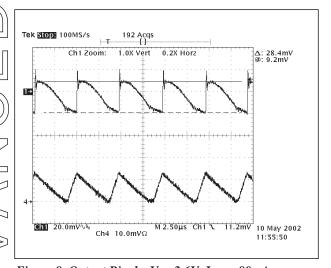


Figure 8. Output Ripple,  $V_{IN}$ =2.6V,  $I_{LOAD}$ =80mA

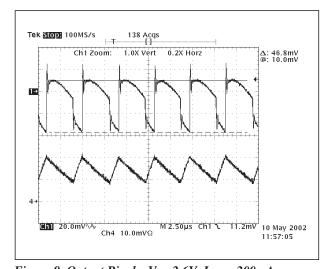


Figure 9. Output Ripple,  $V_{IN}$ =2.6V,  $I_{LOAD}$ =200mA

#### PERFORMANCE CHARACTERISTICS

5V out, refer to the Circuit in Figure 1, T<sub>AMB</sub>=+25°C, R1=374K.

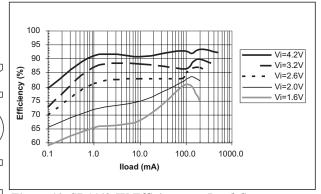


Figure 10. SP6649 5V Efficiency vs. Load Current

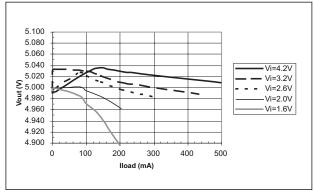


Figure 11. SP6649 5V Line/Load Rejection vs. Load Current

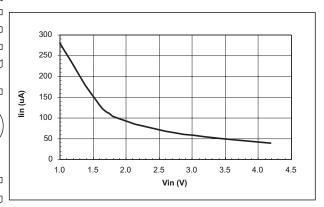


Figure 12. SP6649 5V No Load Battery Current

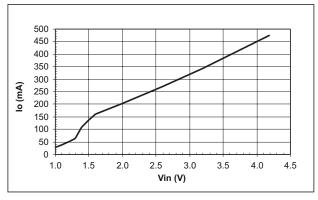


Figure 13. SP6649 5V Maximum Resistive Load Current in Startup

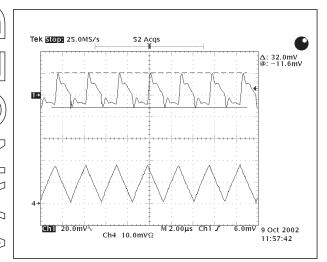


Figure 14. SP6649 5V Output Ripple, Vin=2.6V, Iload=80mA

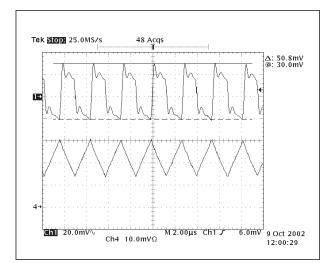


Figure 15. SP6649 5V Output Ripple, Vin=2.6V, Iload=200mA

# **PACKAGE: 10-PIN MSOP**

(ALL DIMENSIONS IN MILLIMETERS)

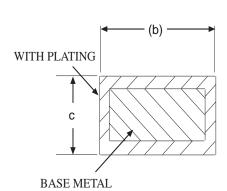


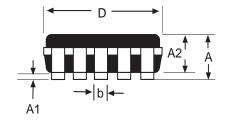
	D — e1 — — — — — — — — — — — — — — — — —	
E/2 E		<b>↑</b> E1
1 2 e		
ntifier must be ind	icated within this	shaded
nensions in (mm)	10-PIN MSOP JEDEC MO-187 (BA) Variation	

Ø1	R1
	R L2
Seating Plane Ø1	← L1 →
area (D/2 * E1/2)	

- Gauge Plane

Dimensions in (mm)	10-PIN MSOP JEDEC MO-187 (BA) Variation		
	MIN	NOM	MAX
A	-	-	1.1
A1	0	-	0.15
A2	0.75	0.85	0.95
b	0.17	-	0.27
С	0.08	-	0.23
D	3.00 BSC		
Е	4.90 BSC		
E1	3.00 BSC		
e	0.50 BSC		
e1	2.00 BSC		
L	0.4	0.60	0.80
L1	-	0.95	-
L2	-	0.25	-
N	-	10	-
R	0.07	-	-
R1	0.07	-	-
Ø	0°		8°
Ø1	0°	-	15°





ORDERING INFORMATION			
Part Number	Operating Temperature Range	Package Type	
	-40°C to +85°C		





SIGNAL PROCESSING EXCELLENCE

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